



FFP08H60S

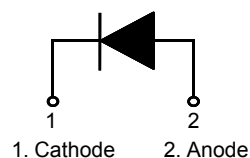
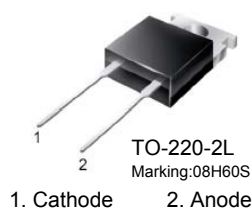
Hyperfast Recovery Power Rectifier

Features

- High Speed Switching
- High Reverse Voltage and High Reliability
- Avalanche Energy Rated
- Low Forward Voltage

Applications

- General Purpose
- Switching Mode Power Supply
- Free-wheeling diode for motor application
- Power switching circuits



Absolute Maximum Ratings (per diode) $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Peak Repetitive Reverse Voltage	600	V
V_{RWM}	Working Peak Reverse Voltage	600	V
V_R	DC Blocking Voltage	600	V
$I_{F(AV)}$	Average Rectified Forward Current @ $T_C = 120^\circ\text{C}$	8	A
I_{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	60	A
T_J, T_{STG}	Operating Junction and Storage Temperature	- 65 to +150	$^\circ\text{C}$

Thermal Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Max	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	2.5	$^\circ\text{C/W}$

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F08H60S	FFP08H60STU	TO-220AC	-	-	50

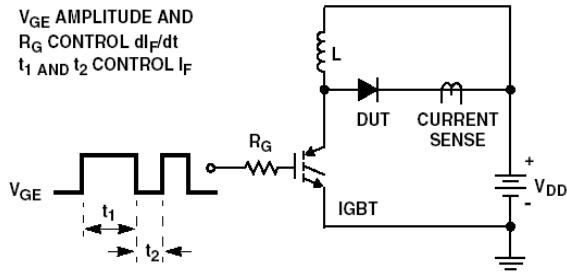
Electrical Characteristics

(per diode) $T_a = 25^\circ\text{C}$ unless otherwise noted

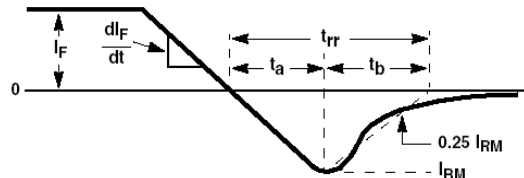
Symbol	Parameter	Min.	Typ.	Max.	Units
V_{FM}^*	$I_F = 8\text{A}$	-	-	2.1	V
	$I_F = 8\text{A}$	-	-	1.7	V
I_{RM}^*	$V_R = 600\text{V}$	-	-	100	μA
	$V_R = 600\text{V}$	-	-	500	μA
t_{rr}	$I_F = 1\text{A}, di/dt = 100\text{A}/\mu\text{s}, V_{CC} = 30\text{V}$	-	-	35	ns
	$I_F = 8\text{A}, di/dt = 100\text{A}/\mu\text{s}, V_{CC} = 390\text{V}$	-	-	45	ns
t_a t_b Q_{rr}	$I_F = 8\text{A}, di/dt = 100\text{A}/\mu\text{s}, V_{CC} = 390\text{V}$	$T_C = 25^\circ\text{C}$	15	-	ns
		$T_C = 25^\circ\text{C}$	16	-	ns
		$T_C = 25^\circ\text{C}$	18.6	-	nC
W_{AVL}	Avalanche Energy ($L = 40\text{mH}$)	20	-	-	mJ

* Pulse Test: Pulse Width=300 μs , Duty Cycle=2%

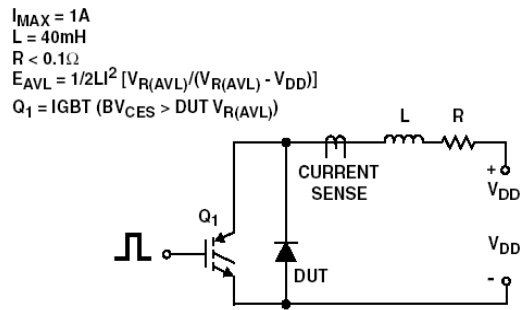
Test Circuit and Waveforms



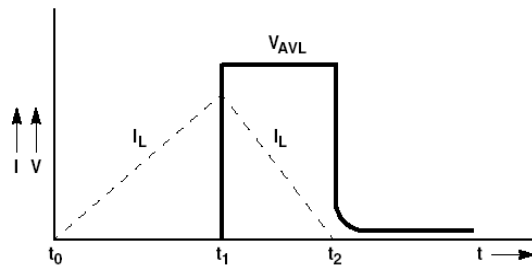
t_{rr} TEST CIRCUIT



t_{rr} WAVEFORMS AND DEFINITIONS



AVALANCHE ENERGY TEST CIRCUIT



AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

Typical Performance Characteristics

Figure 1. Typical Forward Voltage Drop

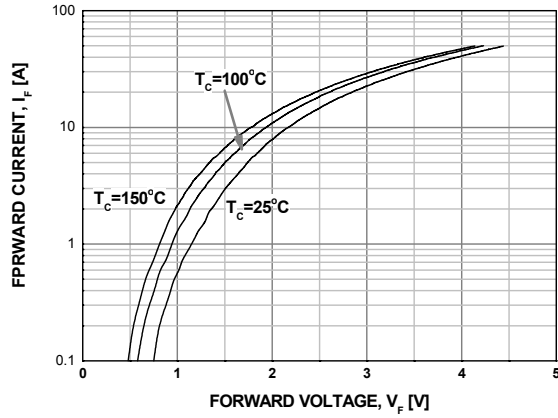


Figure 2. Typical Reverse Current

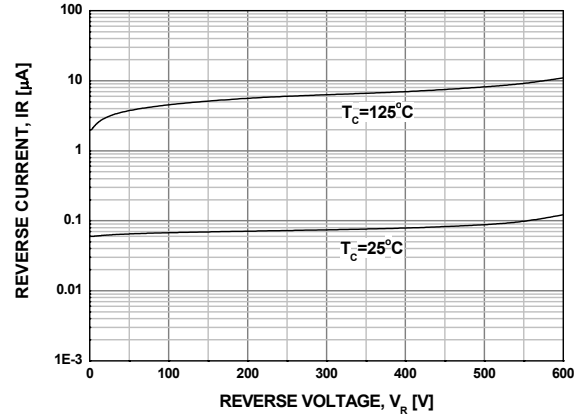


Figure 3. Typical Junction Capacitance

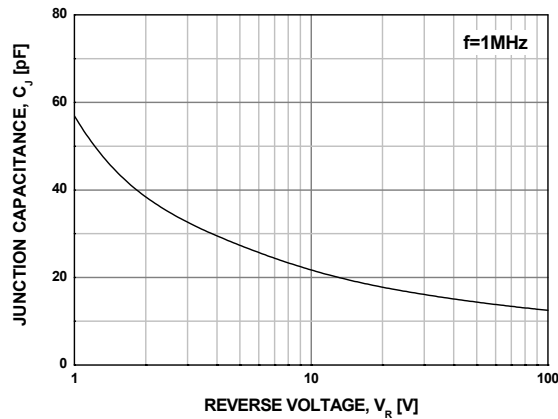


Figure 4. Typical Reverse Recovery Time

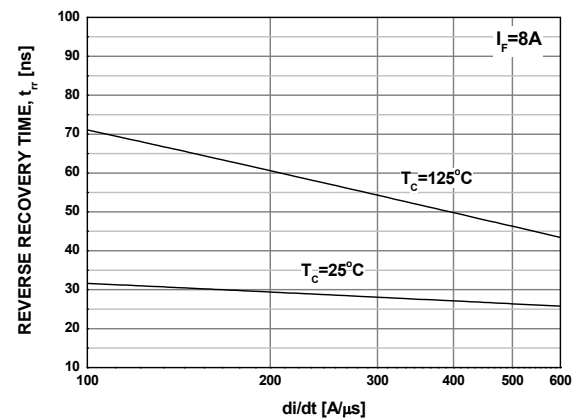


Figure 5. Typical Reverse Recovery Current

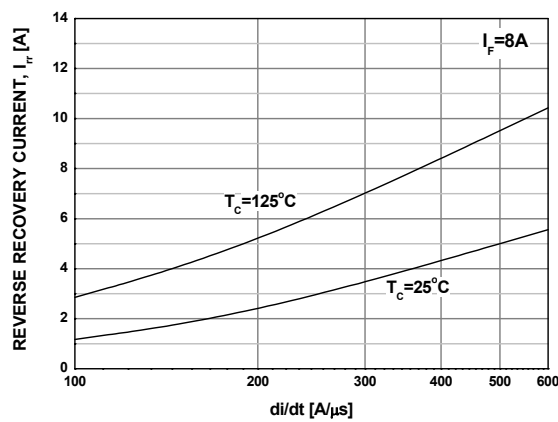
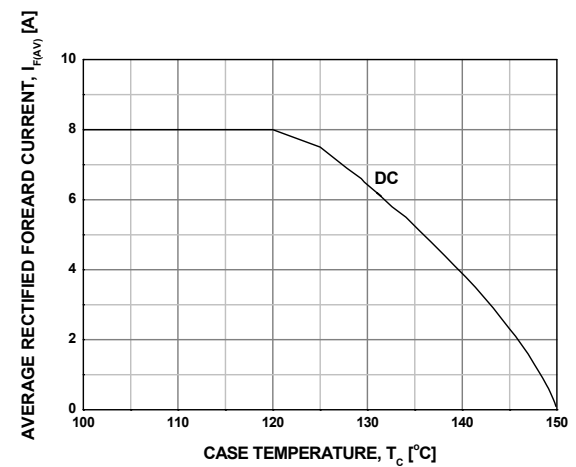
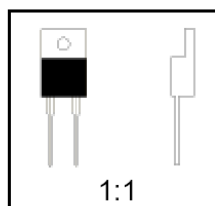


Figure 6. Forward Current Deration Curve



Package Demensions

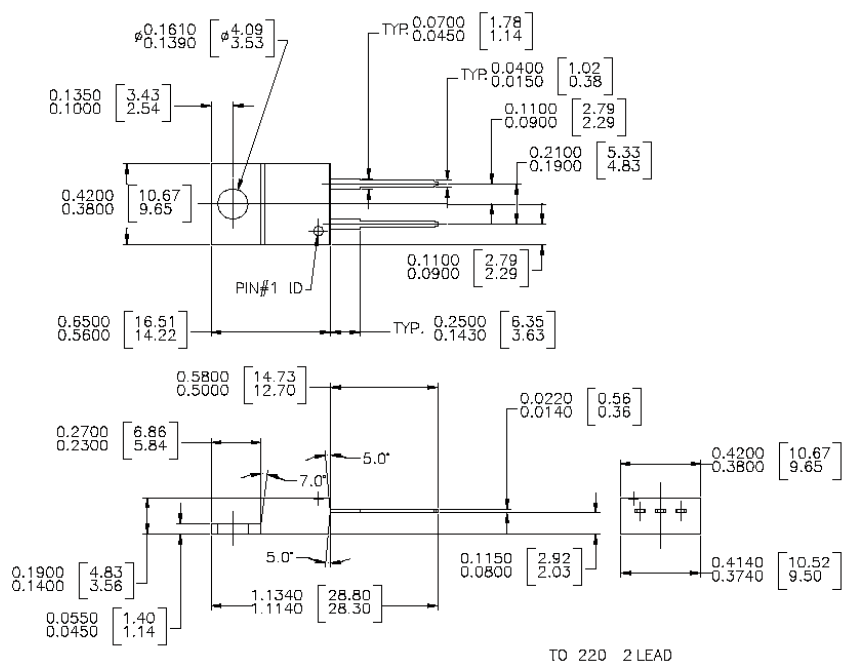
TO-220AC



Scale 1:1 on letter size paper

Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 2.24



NOTE : UNLESS OTHERWISE SPECIFIED

1. STANDARD LEAD FINISH :
200 MICRONS / 5.08 MICRON MINIMUM
LEAD / TIN 15/85 ON OLIN 194 COPPER OR EQUIVALENT
2. DIMENSION BASED ON JEDEC STANDARD TO-220
VARIATION AB, ISSUE J, DATED 3/24/87

Dimensions in Millimeters

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CoolFET™	GlobalOptoisolator™	MicroPak™	QT Optoelectronics™	TinyLogic®
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EnSigna™	ImpliedDisconnect™	OCXPro™	ScalarPump™	UniFET™
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Programmable Active Droop™		PowerEdge™	SuperSOT™-3	

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